



1.EMITTER
2.COLLECTOR
3.BASE

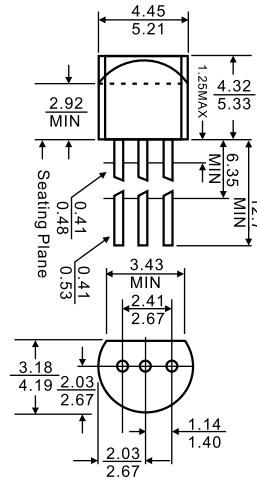
Features

- Power dissipation

MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	50	V
V_{EBO}	Emitter-Base Voltage	5	V
I_c	Collector Current -Continuous	150	mA
P_c	Collector Power Dissipation	400	mW
T_j	Junction Temperature	125	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55-125	$^\circ\text{C}$

TO-92



Dimensions in inches and (millimeters)

ELECTRICAL CHARACTERISTICS ($T_{\text{amb}}=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	$I_C= 100\mu\text{A}, I_E=0$	60			V
Collector-emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	$I_C= 0. 1\text{mA}, I_B=0$	50			V
Emitter-base breakdown voltage	$V_{(\text{BR})\text{EBO}}$	$I_E= 100\mu\text{A}, I_C=0$	5			V
Collector cut-off current	I_{CBO}	$V_{\text{CB}}= 60\text{V}, I_E=0$			0.1	uA
Collector cut-off current	I_{CEO}	$V_{\text{CE}}= 50\text{V}, I_B=0$			0.1	uA
Emitter cut-off current	I_{EBO}	$V_{\text{EB}}=5\text{V}, I_C=0$			0.1	uA
DC current gain	h_{FE}	$V_{\text{CE}}= 6 \text{ V}, I_C= 2\text{mA}$	70		700	
Collector-emitter saturation voltage	$V_{\text{CE}(\text{sat})}$	$I_C=100\text{mA}, I_B=10\text{mA}$			0.25	V
Base-emitter saturation voltage	$V_{\text{BE}(\text{sat})}$	$I_C=100\text{mA}, I_B=10\text{mA}$			1	V
Transition frequency	f_T	$V_{\text{CE}}=10 \text{ V}, I_C= 1\text{mA}$ $f=30\text{MHz}$	80			MHz
Collector Output Capacitance	C_{ob}	$V_{\text{CB}}=10\text{V}, I_E=0$ $f=1\text{MHz}$			3.5	pF
Noise Figure	NF	$V_{\text{CE}}=6\text{V}, I_C=0.1\text{mA}$ $f =1\text{KHz}, R_G=10\text{K}$			10	dB

CLASSIFICATION OF h_{FE}

Rank	O	Y	GR	BL
Range	70-140	120-240	200-400	350-700

Typical Characteristics

